NOAO

ENGINEERING CHANGE ORDER

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BOARD NAME	ME TORRENT TRANSITION UTILITY BRD		RD	ECO#	TRNT-020 DATE 19MAY11		·Υ11
BRD SERL#	ALL REV A	REV _		ART#	TRNT-EL-07-0009-XXX		
PN#		REV _				REV	
ASBLY# _	ΓRNT-EL-04-0009	REV _	Α	PCB#	TRNT-EL-04-1009	REV	Α
BOM# _	TRNT-EL-04-4009	REV _	Α	SCH#	TRNT-EL-04-2009	REV	Α
COGNIZANT ENG	ONR			APPRO	OVD		
					DD AVAIING C A FEFG	OTED:	NEW
REASON FOR MODIFICATION: DRAWINGS AFFECTOR: TRNT-EL-04-0009							REV A1
Removal C35 for VBB stability, TRNT-EL-04-2009 TRNT-EL-04-4009							A1 A1
As a configuration item: addition of diode for reverse voltage protection							
DECCRIPTION	LOE MODIFICATION	1.					
DESCRIPTION OF MODIFICATION: ***This ECO should be done at system level implementation, diode installation direction is							
dependent upon N-CH or P-CH detector type. ***							
1 Pamaya C35 (bottom of board), poor 13 apposite side							
1. Remove C35 (bottom of board), near J3, opposite side.							
TO BE DONE AT SYSTEM BUILD BASED ON DETECTOR TYPE							
Install diode BAV19WS using C35 pads and or nearby vias Orientation of cathode as described below							
Offertation of cathode as described below							
If the application uses a positive Vbb potential i.e. we are dealing with a P-Channel type detector							
then the cathode of the diode points towards the R30 silkscreen marking.							
If the application uses a negative Vbb potential i.e. we are dealing with a N-Channel type detector							
then the cathode of the diode points towards the C35 silkscreen marking.							
This section to be completed by reviewing authority Review Date: Reviewer(s):							
			. ,		75		
Disposition:	Approved	Den	ied		Request Additional Info	rmatio	<u>n</u>